



**ELIZADE UNIVERSITY, ILARA-MOKIN, ONDO STATE**

**FACULTY OF ENGINEERING**

**DEPARTMENT OF ELECTRICAL AND ELECTRONICS  
ENGINEERING**

**FIRST SEMESTER EXAMINATION 2022/2023 ACADEMIC SESSION**

**COURSE TITLE: FUNDAMENTALS OF ELECTRICAL ENGINEERING/BASIC  
ELECTRICAL ENGINEERING I**

**COURSE CODE: GNE 257/GNE 223**

**EXAMINATION DATE: 5<sup>TH</sup> APRIL, 2023**

**COURSE LECTURER: ENGR. OSHIN OLA A**

**HOD'S SIGNATURE**

**TIME ALLOWED: 2 HOURS**

**INSTRUCTIONS:**

- 1. ANSWER ANY FOUR QUESTIONS ONLY**
- 2. SEVERE PENALTIES APPLY FOR MISCONDUCT, CHEATING,  
POSSESSION OF UNAUTHORIZED MATERIALS DURING EXAM.**
- 3. YOU ARE NOT ALLOWED TO BORROW ANY WRITING  
MATERIAL DURING THE EXAMINATION.**

### Question 1

- a. Differentiate between the following pairs of elements: Linear, Non-linear, passive and active elements (4 marks)
- b. Determine the current in the  $8\text{-}\Omega$  resistor using nodal analysis or superposition theorem in the circuit shown in Fig.Q1b (8 marks)

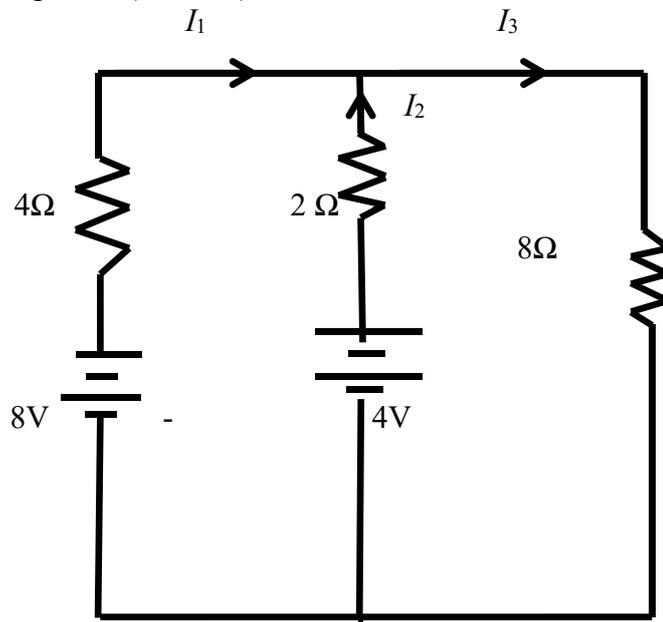


Fig. Q1b

- c ii. Convert the network circuit in Frq.Q1c to an equivalent Thevenin's circuit

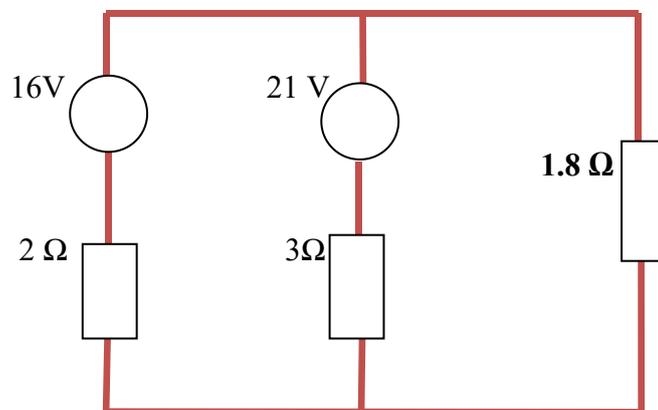


Fig. Q1c

- ii) Determine the current flowing in the  $1.8\text{ }\Omega$  resistor using Thevenin's theorem or Kirchhoff's theorem (8 marks)

### Question 2

- a. i. Briefly describe the following terms:

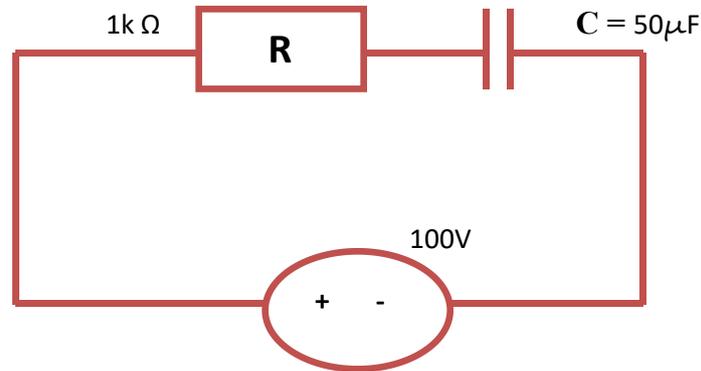
(i) Transient and

(ii) Time constant for a C-R circuit (4 marks)

ii. Describe the transient response of capacitor and resistor voltages and current in a series R-C d.c Circuit (4 marks)

iii. Illustrate the transient growth and decay for the C-R Circuit in Q2a ii (2 marks)

b. The circuit shown in figure Q2b is a  $50\mu\text{F}$  uncharged capacitor connected in series to a  $1\text{k}\Omega$  resistor and the circuit is switched to a  $100\text{V}$ , d.c. supply.



Determine:

- i. the initial current flowing in the circuit,
- ii. the time constant
- iii. the value of current when  $t$  is 50ms and
- iv. the voltage across the resistor 60ms after closing the switch (10 marks)

### Question 3

- a.
- (i) Describe the operation principle of a full wave rectification (4 marks)
  - (ii) Explain the process of removing unwanted ripples from the output of a rectifier (2 marks)
  - (iii) State and explain four (4) important parameters to be considered when choosing a smoothing capacitor for use in a rectifier (4 marks)
- b. i. Determine the current in the  $8\Omega$  resistor using Norton's theorem in the circuit of Fig. Q3b

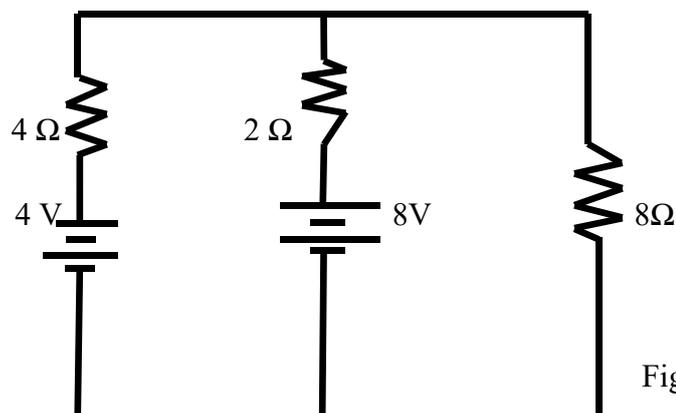
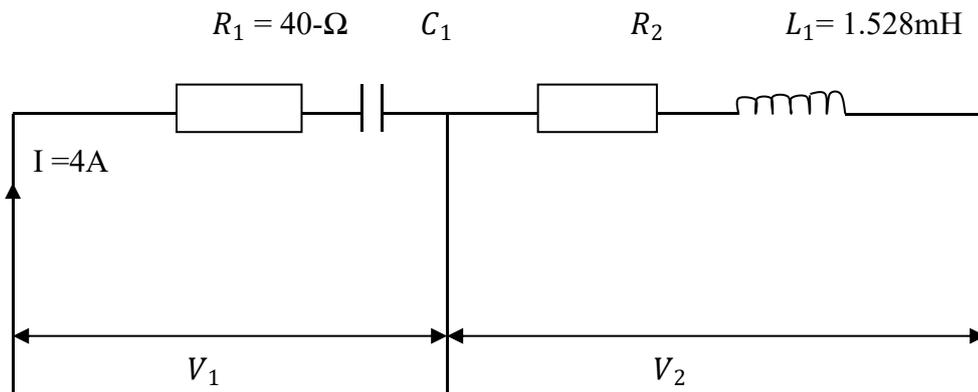


Fig. Q3b

(ii) Hence, determine the power dissipated in the  $8\ \Omega$  resistor (12 marks)

#### Question 4

- a. With the aid of suitable waveform diagrams, describe what you understand by the following
- Leading power factor in a purely capacitive circuit
  - Lagging power factor in a purely inductive circuit (4 marks)
- b. The instantaneous value of two alternating voltages shown in Fig. Q4b are represented by  $V_1 = 236.174 \sin(15710t - 12.68^\circ)$ ,  $V_2 = 147.078 \sin(15710t + 67.38^\circ)$



The supply frequency is 2.5kHz and find a sinusoidal expression representing  $V_1 + V_2$

- Express  $V_1$  in phasor form and in rectangular form
- Express  $V_2$  in phasor form and in rectangular form
- Find a sinusoidal expression representing  $V_1 + V_2$
- Draw the phasor diagram for the circuit (16 marks)

#### Question 5

- a. Explain what you understand by the following terms in relation to PN type semiconductor diode :
- reverse bias
  - forward bias
  - depletion layer
  - contact potential (10 marks)
- a. Corresponding readings of base current,  $I_B$ , and base-emitter voltage,  $V_{BE}$ , for a bipolar junction transistor are given in the table Q5b:

$V_{BE}$ (V)	0	0.0	0.2	0.3	0.4	0.5	0.6	0.7	0.8
$I_B$ ( $\mu$ A)	0	0	0	0	1	3	19	57	130

- Plot the  $I_B/V_{BE}$  characteristic for the device and use it to determine
- the value of  $I_B$  when  $V_{BE}=0.65V$ ,
  - the static value of input resistance when  $V_{BE}=0.65V$ , and
  - the dynamic value of input resistance when  $V_{BE}=0.65V$  (10 marks)

### Question 6

- With reference to a n-p-n transistor, explain briefly what is meant by the term 'transistor action' and why a bipolar junction transistor is so named. (5 marks)
- With the aid of a suitable diagram, explain how a transistor can be used as switch using a light dependent resistor (8 marks)
- Determine the total admittance (Y), Conductance (G) and Inductive Susceptance ( $B_L$ ) in rectangular and polar forms for the circuit in Fig. Q6c

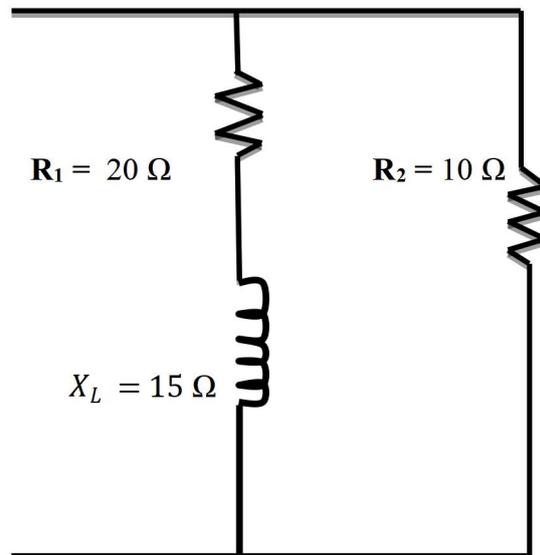


Fig. Q6c

(7 marks)